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[54]	RADIO FREQUENCY OSCILLATOR-MODULATOR CIRCUIT				
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[62]	Division of Ser. No. 949,848, Oct. 10, 1978, Pat. No. 4,214,360, which is a division of Ser. No. 818,838, Jul. 25, 1977, Pat. No. 4,152,671.				
[51]		H03B 5/12; H03C 1/44			
[52]	U.S. Cl	332/31 T; 331/117 R;			
[58]	Field of Sea	332/43 B; 455/108 arch 332/16 T, 31 T, 43 B;			

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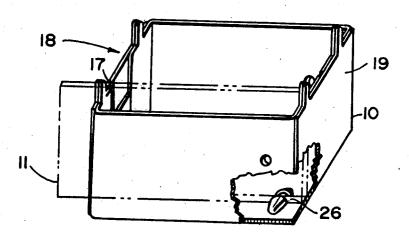
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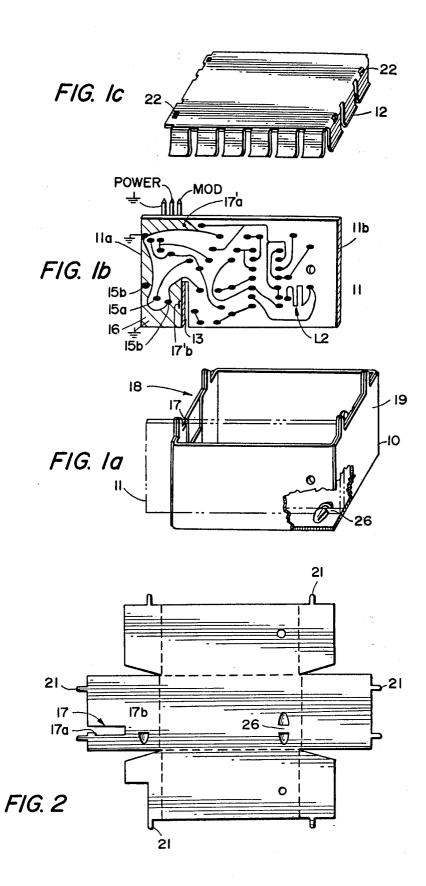
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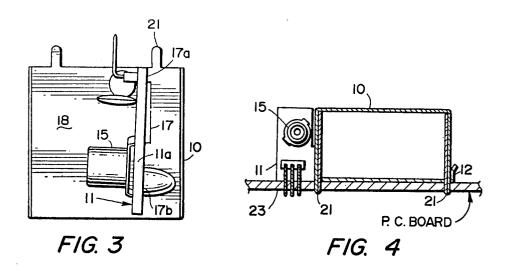
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[57]			ABSTRACT		

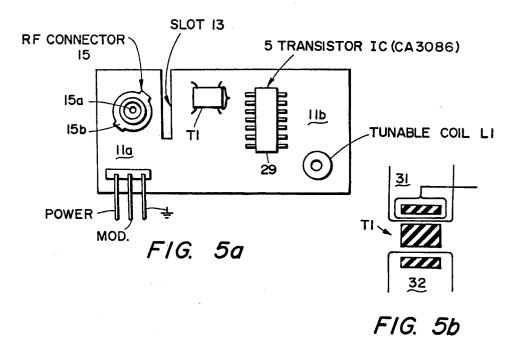
A radio frequency oscillator-modulator for use in a video game includes an oscillator circuit, formed from a first differentially connected, emitter-coupled transistor pair having base/collector cross-coupling, that is dc coupled to the differential inputs of a second differentially connected, emitter-coupled transistor pair that forms the modulator circuit. The modulation signal is applied through a resistance to the connected emitters of the modulator circuit to vary the drive current thereof. The radio frequency oscillator-modulator includes bias circuitry that establishes a low level of operation that provides for great linearity and low R.F. radiation.

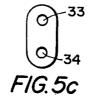
16 Claims, 10 Drawing Figures

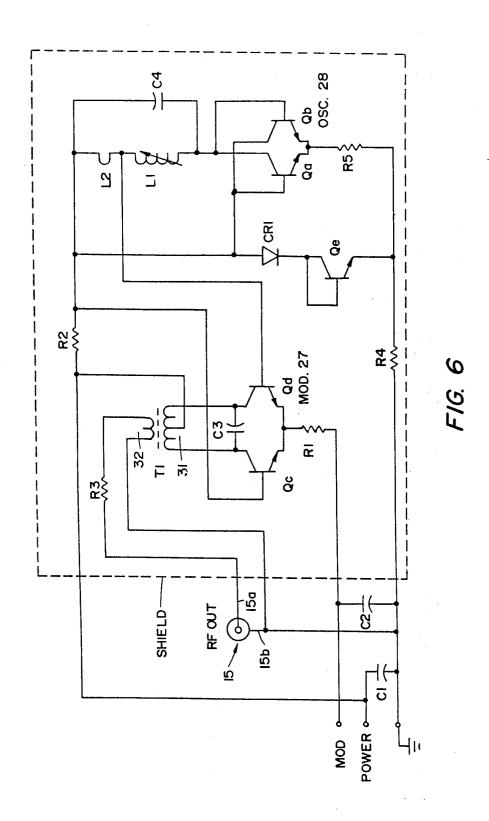












board. The slot means also makes electrical contact with the ground metallization.

RADIO FREQUENCY OSCILLATOR-MODULATOR CIRCUIT

This application is a division of application Ser. No. 5 949,848, filed Oct. 10, 1978, and now U.S. Pat. No. 4,214,360, which in turn was a division of application Ser. No. 818,838, filed July 25, 1977, and now U.S. Pat. No. 4,152,671.

BACKGROUND OF THE INVENTION

The present invention is directed to an oscillatormodulator apparatus and method therefor and more specifically to apparatus for use in video games for

In view of the requirements of the U.S. Federal Communications Commission (FCC) video games which attach to the antenna input terminal of a television receiver must be shielded to prevent excessive electromagnetic radiation. Such video games produce a radio 20 frequency (R.F.) signal which is modulated by the game information. The R.F. signal may correspond to, for example, channel 3 (60-66 MHz) of the television spec-

ponent the construction of an oscillator-modulator which is sufficiently linear, yet produces relatively low levels of R.F. radiation, may be costly. This is illustrated by a standard television transmitter which has separate picture and sound modulators and R.F. oscilla- 30 tors until the transmitting antenna and then in some cases even uses separate antennas.

Finally in any consumer item, cost from both a raw material and production standpoint is crucial. This includes consistency of output characteristics in mass 35 and ground. And on its opposite side, as indicated in production.

One prior design which was used by the assignee of the present application in the video game "HOCKEY PONG" (trademark) consisted of a folded metal box shield containing a printed circuit board. This was 40 found to be inadequate for many of the foregoing reasons.

OBJECTS AND SUMMARY OF THE **INVENTION**

It is, therefore, a general object of the invention to provide an improved radio frequency oscillator-

It is a more specific object of the invention to provide a device as above which is inexpensive yet has a low 50 R.F. level, is easily mass produced with reliable operating characteristics, is highly linear with regard to both picture and audio modulating signals and is relatively insensitive to supply voltage variations.

In accordance with the above objects, there is pro- 55 relatively rigid structure. vided a radio frequency oscillator-modulator which comprises a printed circuit board having mounted therein electrical components forming an oscillator and modulator on a first portion and a coaxial type radio frequency (R.F.) output terminal with ground and R.F. 60 portions mounted on a second board portion. The terminal is effectively surrounded by ground metallization deposited on the board. The board has a slot extending into its interior at least partially separating the metallization and terminal of the second portion from the re- 65 maining first portion of the board. A metal box shaped R.F. shield contains the second portion of the board and has a side with slot means for mating with the slot of the

BRIEF DESCRIPTION OF THE DRAWINGS

FIGS. 1a-c are perspective exploded views of a R.F. oscillator-modulator embodying the present invention; FIG. 2 is a plan view of a metal cutout which is folded to form the box of FIG. 1a;

FIG. 3 is an assembled end view of FIGS. 1a and 1b; FIG. 4 is a simplified cross sectional view of the assembly of FIGS. 1a-c inserted in a printed circuit

FIG. 5a is a simplified plan view of the opposite side of FIG. 1b:

FIGS. 5b and 5c are cross-sectional and end views of a component of FIG. 5a; and

FIG. 6 is a circuit schematic of FIG. 1b.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENT

The radio frequency oscillator-modulator of the present invention consists of three components shown in the exploded views of FIGS. 1a, 1b and 1c. These are a folded metal box shaped radio frequency (R.F.) shield Where the game information includes an audio com- 25 10, a printed circuit board 11 having all of the electrical components thereon and the metal lid or cap 12 of FIG. 1c for forming a total electromagnetic shield in combination with box 10 for at least a portion of printed circuit board 11.

> Specifically, board 11 includes a first portion 11a and a second portion 11b which are separated by the slot 13 extending from the bottom edge into the interior of the printed circuit board. Portion 11a carries all of the input terminals; specifically, power, the modulation signal FIG. 5a a R.F. output terminal or connector 15 which has a coaxial inner R.F. terminal 15a and an outer grounded shield 15b. The connection of 15a is ilustrated on the opposite side in FIG. 1b. The outer grounded shield of the coaxial terminal is connected to the ground metallization 16 which extensively covers the portion 11a of printed circuit board 11 and effectively surrounds R.F. terminal 15.

Shield box 10, as best shown in FIG. 2, includes a slot 45 17 which mates with the board slot 13 as shown by the phantom view of board 11 in FIG. 1a. FIG. 2 is a precut metal sheet with the fold lines being shown which will form the shield box 10. When the box is folded, the sheet metal forming the ends 18 and 19 of the box are generously overlapped to effectively reduce R.F. leakage. The foldout of FIG. 2 also includes several tabs 21 which in the folded up state shown in FIG. 1a form adjacent pairs and in combination with the holes 22 in lid 12 through which the tabs 21 will extend forms a

Also in its assembled state the tabs 21, as illustrated in FIG. 4, may be used to mount the entire modulatoroscillator on a printed circuit board 23. Here the tabs may be soldered to provide a very effective ground at four locations to the printed circuit board 23.

As best illustrated in FIG. 2 slot 17 includes at one end a nub 17a and near the opposite end a second nub 17b. As best shown in FIG. 3 when the board 11 is inserted in slot 17 the nub 17b provides a twisting action twisting the board portion 11a with respect to the portion 11b. This causes a very effective electrical contact to be made to the ground metallization 16 at both nubs 17a and 17b. These points are indicated in FIG. 1b as 3

17'a and 17'b. In other words, the twisting action provided by the slot and the nubs force the ground metallization to scrape along the nubs 17a, b to produce two electrical connections. A further retention slot 26 formed in the bottom of the box is illustrated in FIG. 1a 5 and FIG. 2 to provide for locating printed circuit board 11 as it is mated or inserted into box 10.

The extensive metallization 16 which effectively surrounds the radio frequency output terminal 15 and the fact that it is grounded reduces the radio frequency radiation of the external portion 11a of the printed circuit board to a minimum.

Referring now to the circuit of FIG. 6 in conjunction with the actual showing of some of the components of FIGS. 5a through 5c, in general the circuit includes a modulator 27 having a differentially coupled pair of transistors Q_c and Q_d and an oscillator 28 having a pair of differentially connected transistors Q_a and Q_b . There is a fifth transistor, Q_c which is connected as a diode and all of the five transistors are contained in a five transistor integrated circuit 29 (FIG. 5a) which is of the industry type CA3086. The transistor pairs Q_a , Q_b and Q_c , Q_d all have their bases dc coupled together and in addition transistors Q_a and Q_b have an effective zero volts bias between the base and collector of each of them.

The oscillator transistors Q_a and Q_b utilize feedback from the collector of Q_a to the base of Q_b to provide the oscillation. L1 is a tunable coil to adjust the oscillating frequency along with the fixed inductor L2 with the remainder of the tank circuit including capacitor C4. The oscillator takeoff is between L1 and L2. L2 is quite small and therefore is incorporated as part of printed circuit board 11.

Power supply regulation means which makes the circuit relatively immune to variations such as from one to nine volts in supply voltage includes the diode connected transistor Q_e and series connected diode CR1. The transistor Q_e acts like a Zener voltage regulator and, of course, since it is on the same integrated circuit chip matches exactly the characteristics of Q_a and Q_b . The voltage drop across resistor R5 determines the current and is in effect controlled by the drop across diode CR1 which is 7/10 volt. Thus, variations in the power supply voltage will not affect the operation of 45 the oscillator circuit.

Resistor R2 provides a minimal 1/10 volt drop between the power input and the oscillator circuit 28. The resistor R4 is for the purpose of minimizing current in the diode CR1 and is not critical.

The modulator 27 formed by differential pair Q_c and Q_d is a transconductance type modulator utilizing the current limiting characteristics of this configuration. Modulation is supplied as a current sink at the modulation (MOD.) input through resistor R1 with the radio 55 frequency potential appearing at the transformer T1 primary 31. This primary is center tapped to the power input. High frequency signals are filtered out by parallel connected bypass capacitor C3. For example, signals which are twice the carrier frequency. Transformer 60 secondary 32 supplies the radio frequency potential to R.F. output jack or terminal 15.

Transformer T1 is also shown in FIGS. 5a through 5c and is actually a ferrite balun which includes two holes 33 and 34. Hole 33 is for the primary coil 31 and hole 34 65 for the secondary 32. Such ferrite transformer provides a low frequency cutoff point by reason of its leakage reactance so that the transformer T1 in combination

with high frequency bypass capacitor C3 effectively acts as a bandpass filter.

OPERATION

In actual use the oscillator-modulator of the present invention would have applied to its modulation terminal the modulation signal. The oscillator 28 provides the radio frequency signal to be modulated in the form of a channel 3 television frequency band of from 60 to 66 MHz with the picture carrier signal being at 61.25 MHz. Also contained in this modulation signal is a frequency modulated sound signal having a conventional carrier of 4.50 MHz. Thus, the resultant modulated radio frequency signal produced by the modulator 27 will have a frequency component at 65.75 MHz. Because of both the linearity of the modulator of the present invention and the fact that proper filtering and shielding is provided, picture and sound modulation can be done in a single modulator.

To summarize from a filtering standpoint, the transformer T1 which, as noted above, is formed from a ferrite balun to operate as a bandpass filter with capacitor C3 because its leakage reactance cuts out lower frequencies and the bypass capacitor C3 eliminates higher frequencies. From a linearity standpoint the zero volts bias achieved by connecting collectors to the bases and the common base connection provides relatively linear operation. In addition the Zener diode like voltage regulation utilizing the diode CR1 and diode connected transistor Qe determines a constant current through the oscillator. In addition, as discussed above, it also makes the oscillator insensitive to supply voltage changes of the range, for example, from 1 to 9 volts. This is especially important where the oscillator modulator may be used in many different types of video games in many environments. Finally from a electromagnetic radiation point of view, the oscillator's peak to peak or swing voltage is also limited by the zero bias voltage between base and collector and the common base connection.

From a cost standpoint, this type of biasing eliminates the many components normally required for biasing and is very inexpensive. From a construction standpoint, once the tunable coil L1 is adjusted at the factory the unit maintains its frequency stability throughout its life. Moreover, component variations as, for example, in the five transistor integrated circuit unit of even a relatively large magnitude can be tolerated. Therefore such IC unit may be of relatively low cost.

Thus an improved radio frequency oscillator-modulator has been provided.

What is claimed is:

- 1. An oscillator circuit comprising:
- a first transistor having a base, an emitter and a collector:
- a second transistor having a base dc coupled to the base of the first transistor and directly coupled to the collector of the first transistor, a collector directly coupled to the base of the first transistor and an emitter coupled to the emitter of the first transistor;
- a resonant circuit having first and second terminals for providing a relatively high impedance between the terminals at one frequency, the first terminal coupled to the collector of the first transistor and the second terminal coupled to the collector of the second transistor;

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current regulating means comprising a first resistor having a first terminal coupled to the emitters of the first and second transistors and having a second terminal; and a diode-coupled transistor coupled in series with a forward biased diode, the series coupled diode-coupled transistor and forward biased diode being connected between the base of the first transistor and the second terminal of the first resistor; and

circuit means for connecting a DC voltage between the base of the first transistor and the second terminal of the first resistor.

2. An oscillator circuit as in claim 1 wherein the dc coupling between the bases of the first and second transistors is provided by the resonant circuit.

3. An oscillator circuit as in claim 1 wherein the resonant circuit comprises a first inductor and a capacitor connected between the first and second terminals of the resonant circuit in parallel circuit configuration.

4. The oscillator circuit of claim 3, wherein the first inductor comprises second and third inductors connected in series circuit configuration, a lead of the second inductor being connected to the first terminal of the resonant circuit, and a lead of the third inductor being 25 connected to the second terminal.

5. An oscillator-modulator circuit comprising the oscillator circuit of claim 1 or 3 and further comprising a differential modulator circuit having a differential input coupled across a reactive element of the resonant 30 circuit.

- 6. An oscillator-modulator circuit as in claim 5 wherein the differential modulator circuit comprises a third transistor having a base, a collector and an emitter; a fourth transistor having a base DC coupled to the base 35 of the third transistor, a collector, and an emitter coupled to the emitter of the third transistor, the bases of the third and fourth transistors forming the differential input of the differential modulator circuit; bias means for providing a DC voltage between the collector and 40 base of each of the third and fourth transistors; input means for coupling a modulating signal to the emitters of the third and fourth transistors; and a transformer having first and second terminals on an input winding 45 coupled to the collectors of the third and fourth transistors respectively, and an output winding operatively coupled to the input winding having first and second output terminals.
- 7. An oscillator-modulator circuit as in claim 6 50 wherein the diode coupled transistor is matched to the first and second transistors.
- 8. An oscillator-modulator circuit as in claim 7 further comprising a second resistor having a first terminal and having a second terminal coupled to the base of the 55 first transistor, the input winding of the transformer having a center tap coupled to the first terminal of the second resistor.
- 9. An oscillator-modulator circuit as in claim 8 further comprising a third resistor having a first terminal 60 coupled to the emitters of the third and fourth transis-

tors and having a second terminal coupled to receive said modulation signal.

- 10. An oscillator circuit as in claim 1 wherein the diode coupled transistor is matched to the first and second transistors.
- 11. A radio frequency oscillator-modulator, comprising:

a modulator including a first differentially connected, emitter-coupled transistor pair, the emitters of the first transistor pair being coupled to a modulator input terminal for receiving a modulating signal;

an oscillator for generating a radio frequency signal including a second pair of differentially connected, emitter-coupled transistors having base leads coupled to one another by a resonant circuit, the base lead of each transistor of the second pair being connected to the collector of the other transistor of the second pair;

coupling means for communicating the radio frequency signal to the modulator;

bias means for establishing a predetermined potential including first and second terminals, a fifth transistor connected as a diode, and a first diode, the fifth transistor and first diode being connected in series between the first and second terminals, the bases of the first and second pairs of transistors being dc coupled to the first terminal of the biasing means, the emitters of the second pair of transistors being connected through a load-resistor to the second terminal:

circuit means coupled to the first and second terminals of the bias means for providing a DC voltage thereto; and

output means coupled to the collector of at least one of the modulator transistors for providing a modulated oscillator output signal.

- 12. The radio frequency oscillator-modulator of claim 11, including a unitary integrated circuit forming said first and second transistor pairs and said fifth transistor.
- 13. The radio frequency oscillator-modulator of claim 12, including an output transformer formed from a ferrite balun having a primary winding connected between the collectors of the first transistor pair.
- 14. The radio frequency oscillator-modulator of claim 11, wherein said resonant circuit includes a series circuit configuration comprising first and second inductors, the first inductor having first and second leads respectively connected to the bases of the first pair of transistors.
- 15. The radio frequency oscillator-modulator of claim 11, including means for interconnecting the second pair of transistors to establish an effective zero volt bias between the base lead and the collector lead of each transistor of said second pair of transistors.
- 16. The radio frequency oscillator-modulator of claim 11, wherein each of the transistors of the first transistor pair includes base leads; and including means for dc coupling the base leads of the first and second transistor pairs to one another.